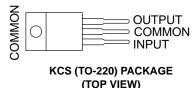
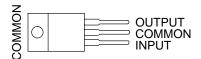
μΑ7800 SERIES POSITIVE-VOLTAGE REGULATORS

SLVS056I - MAY 1976 - REVISED FEBRUARY 2003

- 3-Terminal Regulators
- Output Current up to 1.5 A
- Internal Thermal-Overload Protection

KC (TO-220) PACKAGE (TOP VIEW)

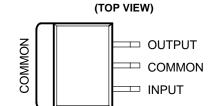




High Power-Dissipation Capability

KTE PACKAGE

- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation



description/ordering information

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 1.5 A of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents, and also can be used as the power-pass element in precision regulators.

ORDERING INFORMATION

ТЈ	V _{O(NOM)} (V)	PACKAGET		ORDERABLE PART NUMBER	TOP-SIDE MARKING
		POWER-FLEX (KTE)	Reel of 2000	μΑ7805CKTER	μA7805C
	5	TO-220 (KC)	Tube of 50	μΑ7805CKC	A790EC
		TO-220, short shoulder (KCS)	Tube of 20	μΑ7805CKCS	μA7805C
		POWER-FLEX (KTE)	Reel of 2000	μΑ7808CKTER	μA7808C
	8	TO-220 (KC)	Tube of 50	μΑ7808CKC	A7000C
		TO-220, short shoulder (KCS)	Tube of 20	μΑ7808CKCS	μA7808C
	10	POWER-FLEX (KTE)	Reel of 2000	μΑ7810CKTER	μA7810C
0°C to 125°C	10	TO-220 (KC)	Tube of 50	μΑ7810CKC	μA7810C
0 C to 125 C		POWER-FLEX (KTE)	Reel of 2000	μΑ7812CKTER	μA7812C
	12	TO-220 (KC)	Tube of 50	μΑ7812CKC	μΑ7812C
		TO-220, short shoulder (KCS)	Tube of 20	μΑ7812CKCS	μΑ/612C
		POWER-FLEX (KTE)	Reel of 2000	μΑ7815CKTER	μA7815C
	15	TO-220 (KC)	Tube of 50	μΑ7815CKC	A7945C
		TO-220, short shoulder (KCS)	Tube of 20	μΑ7815CKCS	μA7815C
	24	POWER-FLEX (KTE)	Reel of 2000	μΑ7824CKTER	μA7824C
	24	TO-220 (KC)	Tube of 50	μΑ7824CKC	μA7824C

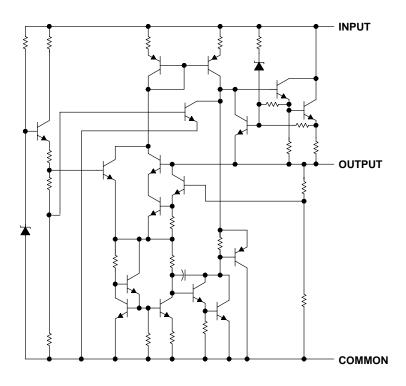
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



schematic



absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Input voltage, V _I : μA7824C		/
All others		/
Package thermal impedance, θ_{JA} (see Notes 1 and 2):	KC/KCS package 25°C/W	V
	KTE package	V
Operating virtual junction temperature, T _J)
Lead temperature 1,6 mm (1/16 inch) from case for 10	seconds 260°C)
Storage temperature range, T _{stq})

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			MIN	MAX	UNIT
	μΑ	\7805C	7	25	
	μΑ	7808C	10.5	25	
V _I Input voltage	7810C	12.5	28	V	
	/ _I Input voltage	14.5	30	V	
		7815C	17.5	30	
	μΑ	17824C	27	38	
lo	Output current			1.5	Α
TJ	Operating virtual junction temperature μΑ	7800C series	0	125	°C



NOTES: 1. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-5.

SLVS056I - MAY 1976 - REVISED FEBRUARY 2003

electrical characteristics at specified virtual junction temperature, V_I = 10 V, I_O = 500 mA (unless otherwise noted)

DADAMETED	TEST CO	NOITIONS	_ +	μ Α7805C			UNIT
PARAMETER	TEST CO	NDITIONS	TJ [†]	MIN	TYP	MAX	UNII
Output voltage	$I_0 = 5 \text{ mA to 1 A},$	$V_{ } = 7 \text{ V to } 20 \text{ V},$	25°C	MIN TYP MAX 4.8 5 5.2 4.75 5.25 3 100 1 50 62 78 15 100 5 50 0.017 -1.1 m 40 2 4.2 8 1	V		
Output voltage	P _D ≤ 15 W		0°C to 125°C	4.75		5.25	V
Input voltage regulation	V _I = 7 V to 25 V		25°C		3	100	mV
Input voltage regulation	V _I = 8 V to 12 V		7 25 0		1	50	IIIV
Ripple rejection	V _I = 8 V to 18 V,	f = 120 Hz	0°C to 125°C	62	78		dB
Output voltage regulation	$I_0 = 5 \text{ mA to } 1.5 \text{ A}$		25°C		15	100	mV
Output voltage regulation	I _O = 250 mA to 750 mA		25-0		5	50	IIIV
Output resistance	f = 1 kHz		0°C to 125°C		0.017		Ω
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$		0°C to 125°C		-1.1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		25°C		40		μV
Dropout voltage	I _O = 1 A		25°C		2		V
Bias current			25°C		4.2	8	mA
Bias current change	V _I = 7 V to 25 V I _O = 5 mA to 1 A		2004 42500			1.3	mA
bias current change			0°C to 125°C			0.5] "IA
Short-circuit output current			25°C		750		mA
Peak output current			25°C		2.2		Α

[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	_ +	μ	A7808C		UNIT
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNII
Output voltage	$I_O = 5 \text{ mA to 1 A}, \qquad V_I = 10.5 \text{ V to 23 V},$	25°C	7.7	8	8.3	V
Output voltage	P _D ≤ 15 W	0°C to 125°C	7.6		8.4	V
Input voltage regulation	V _I = 10.5 V to 25 V	25°C	6 160		mV	
input voltage regulation	V _I = 11 V to 17 V	25 C		2	80	IIIV
Ripple rejection	V _I = 11.5 V to 21.5 V, f = 120 Hz	0°C to 125°C	55	72		dB
Output voltage regulation	$I_O = 5$ mA to 1.5 A	25°C		12	160	mV
Output voltage regulation	I _O = 250 mA to 750 mA	25 C		4	80	
Output resistance	f = 1 kHz	0°C to 125°C		0.016		Ω
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$	0°C to 125°C		-0.8		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		52		μV
Dropout voltage	I _O = 1 A	25°C		2		V
Bias current		25°C		4.3	8	mA
Bias current change	V _I = 10.5 V to 25 V	0°C to 125°C			1	mA
	$I_O = 5$ mA to 1 A	0 0 10 125 0			0.5	IIIA
Short-circuit output current		25°C		450		mA
Peak output current		25°C		2.2		Α

[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.



SLVS056I - MAY 1976 - REVISED FEBRUARY 2003

electrical characteristics at specified virtual junction temperature, V_I = 17 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CON	DITIONE	- +	μ	A7810C		UNIT
PARAMETER	IESI CON	DITIONS	TJ [†]	MIN	TYP	MAX	UNII
Output voltage	$I_{O} = 5 \text{ mA to 1 A},$	$V_{I} = 12.5 \text{ V to } 25 \text{ V},$	25°C	9.6	10	10.4	V
Output voltage	P _D ≤ 15 W		0°C to 125°C	9.5	10	10.5	V
Input voltage regulation	V _I = 12.5 V to 28 V		25°C		7	200	mV
Input voltage regulation	V _I = 14 V to 20 V		25°C		2	100	IIIV
Ripple rejection	V _I = 13 V to 23 V,	f = 120 Hz	0°C to 125°C	55	71		dB
Output valtage regulation	I _O = 5 mA to 1.5 A I _O = 250 mA to 750 mA		25°C		12	200	-l m∨ l
Output voltage regulation					4	100	
Output resistance	f = 1 kHz		0°C to 125°C		0.018		Ω
Temperature coefficient of output voltage	I _O = 5 mA		0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		25°C		70		μV
Dropout voltage	I _O = 1 A		25°C		2		V
Bias current			25°C		4.3	8	mA
Discourant shares	V _I = 12.5 V to 28 V I _O = 5 mA to 1 A		0°C to 125°C			1	A
Bias current change			0.0 10 125.0	0.5		mA	
Short-circuit output current			25°C		400		mA
Peak output current			25°C		2.2		Α

[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 19 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIO	TEST CONDITIONS		μ	UNIT		
PARAMETER	TEST CONDITIO	JNS	TJ [†]	MIN	TYP	MAX	UNII
Output voltage	$I_O = 5 \text{ mA to 1 A}, V_I =$: 14.5 V to 27 V,	25°C	11.5	12	12.5	V
Output voltage	P _D ≤ 15 W		0°C to 125°C	11.4		12.6	V
Input voltage regulation	V _I = 14.5 V to 30 V		25°C		10	240	mV
Input voltage regulation	V _I = 16 V to 22 V		25°C		3	120	IIIV
Ripple rejection	$V_I = 15 \text{ V to } 25 \text{ V}, \qquad f = 1$	120 Hz	0°C to 125°C	55	71		dB
Output valta as assulation	I _O = 5 mA to 1.5 A I _O = 250 mA to 750 mA		25°C		12	240	m∨
Output voltage regulation			25-0		4	120	
Output resistance	f = 1 kHz		0°C to 125°C		0.018		Ω
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$		0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		25°C		75		μV
Dropout voltage	I _O = 1 A		25°C		2		V
Bias current			25°C		4.3	8	mA
Dies surrent shangs	V _I = 14.5 V to 30 V I _O = 5 mA to 1 A					1	A
Bias current change			0°C to 125°C	0.5		mA	
Short-circuit output current		·	25°C		350		mA
Peak output current			25°C		2.2		Α

[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-µF capacitor across the input and a 0.1-µF capacitor across the output.



SLVS056I - MAY 1976 - REVISED FEBRUARY 2003

electrical characteristics at specified virtual junction temperature, V_I = 23 V, I_O = 500 mA (unless otherwise noted)

DADAMETED	TEST COMPITIONS	-+	μ Α7815C			UNIT
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNII
Output voltage	$I_O = 5 \text{ mA to 1 A}, \qquad V_I = 17.5 \text{ V to 30 V},$	25°C	14.4	15	TYP MAX 15 15.6 15.75 11 300 3 150 70 12 300 4 150 0.019	V
Output voltage	P _D ≤ 15 W	0°C to 125°C	14.25		15.75	V
Input voltage regulation	V _I = 17.5 V to 30 V	25°C	11 300		mV	
Input voltage regulation	V _I = 20 V to 26 V	25 0		3	150	IIIV
Ripple rejection	V _I = 18.5 V to 28.5 V, f = 120 Hz	0°C to 125°C	54	70		dB
Output voltage regulation	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$	25°C		12	300	mV
Output voltage regulation	I _O = 250 mA to 750 mA	25 C		4	150	IIIV
Output resistance	f = 1 kHz	0°C to 125°C		0.019		Ω
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$	0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		90		μV
Dropout voltage	I _O = 1 A	25°C		2		V
Bias current		25°C		4.4	8	mA
Bias current change	V _I = 17.5 V to 30 V	0°C to 125°C			1	mA
Bias current change	$I_O = 5$ mA to 1 A	0 0 10 125 0			0.5	IIIA
Short-circuit output current		25°C		230		mA
Peak output current		25°C		2.1		Α

[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 33 V, I_O = 500 mA (unless otherwise noted)

DADAMETED	TEST COA	IDITIONS	_ +	μ Α7824C			UNIT
PARAMETER	TEST CON	IDITIONS	TJ [†]	MIN	TYP	MAX	UNII
Output voltage	$I_0 = 5 \text{ mA to 1 A},$	V _I = 27 V to 38 V,	25°C	23	24	25	V
Output voltage	P _D ≤ 15 W		0°C to 125°C	22.8		25.2	V
Input voltage regulation	V _I = 27 V to 38 V		25°C	2500		480	mV
Input voltage regulation	V _I = 30 V to 36 V] 25 C		6	240	IIIV
Ripple rejection	V _I = 28 V to 38 V,	f = 120 Hz	0°C to 125°C	50	66		dB
Output valtage regulation	I _O = 5 mA to 1.5 A		25°C	12	480) mV	
Output voltage regulation	I _O = 250 mA to 750 mA		25.0		4	240	IIIV
Output resistance	f = 1 kHz		0°C to 125°C		0.028		Ω
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$		0°C to 125°C		-1.5		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		25°C		170		μV
Dropout voltage	I _O = 1 A		25°C		2		V
Bias current			25°C		4.6	8	mA
Bias current change	V _I = 27 V to 38 V		0°C to 125°C			1	mA
bias current change	I _O = 5 mA to 1 A		0 0 10 125 0			0.5	IIIA
Short-circuit output current			25°C		150		mA
Peak output current		_	25°C		2.1		Α

[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.



APPLICATION INFORMATION

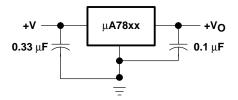


Figure 1. Fixed-Output Regulator

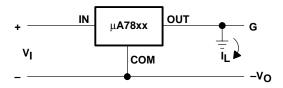
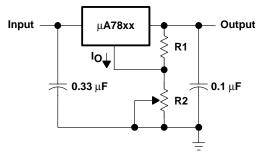


Figure 2. Positive Regulator in Negative Configuration (V_I Must Float)



NOTE A: The following formula is used when V_{XX} is the nominal output voltage (output to common) of the fixed regulator:

$$V_{O} = V_{xx} + \left(\frac{V_{xx}}{R1} + I_{Q}\right)R2$$

Figure 3. Adjustable-Output Regulator

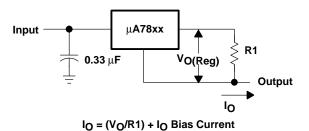


Figure 4. Current Regulator

APPLICATION INFORMATION

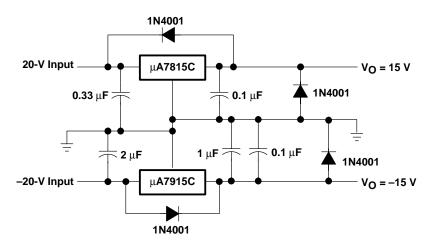


Figure 5. Regulated Dual Supply

operation with a load common to a voltage of opposite polarity

In many cases, a regulator powers a load that is not connected to ground but, instead, is connected to a voltage source of opposite polarity (e.g., operational amplifiers, level-shifting circuits, etc.). In these cases, a clamp diode should be connected to the regulator output as shown in Figure 6. This protects the regulator from output polarity reversals during startup and short-circuit operation.

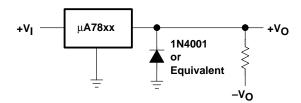


Figure 6. Output Polarity-Reversal-Protection Circuit

reverse-bias protection

Occasionally, the input voltage to the regulator can collapse faster than the output voltage. This can occur, for example, when the input supply is crowbarred during an output overvoltage condition. If the output voltage is greater than approximately 7 V, the emitter-base junction of the series-pass element (internal or external) could break down and be damaged. To prevent this, a diode shunt can be used as shown in Figure 7.

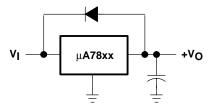
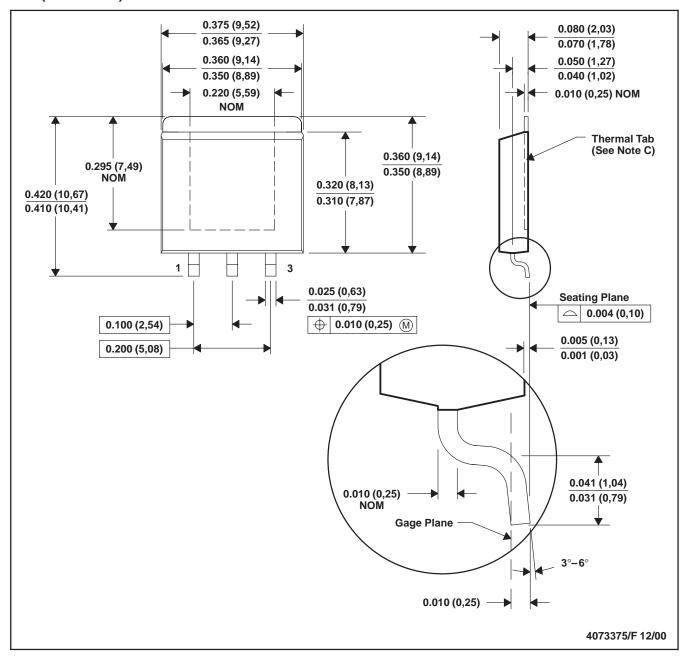


Figure 7. Reverse-Bias-Protection Circuit

KTE (R-PSFM-G3)

PowerFLEX™ PLASTIC FLANGE-MOUNT

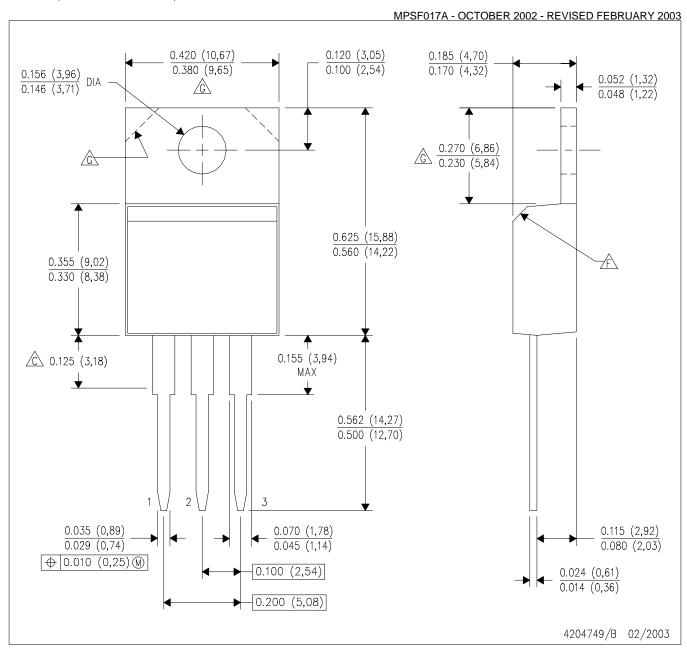


NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. The center lead is in electrical contact with the thermal tab.
- D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
- E. Falls within JEDEC MO-169

PowerFLEX is a trademark of Texas Instruments.





NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.

Lead dimensions are not controlled within this area.

- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.

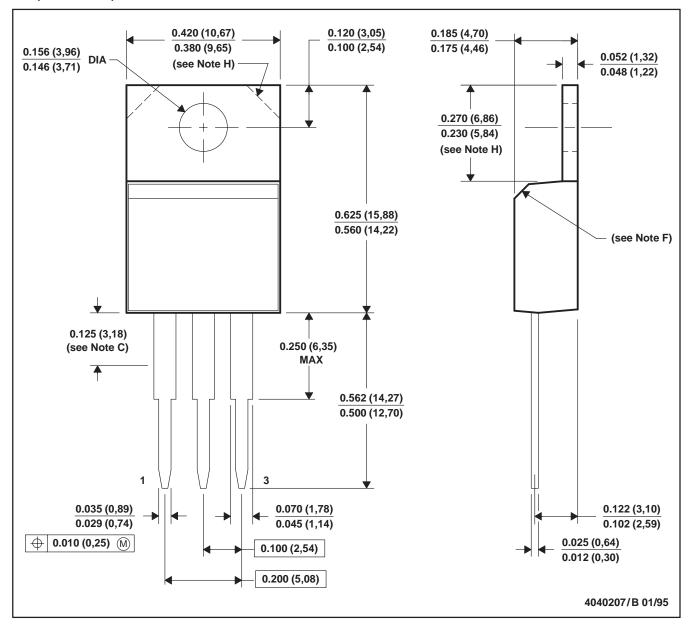
The chamfer is optional.

Tab contour optional within these dimensions.

H. Falls within JEDEC TO-220 variation AB.

KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- F. The chamfer is optional.
- G. Falls within JEDEC TO-220AB
- H. Tab contour optional within these dimensions



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third—party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Mailing Address:

Texas Instruments
Post Office Box 655303
Dallas, Texas 75265

Copyright © 2003, Texas Instruments Incorporated

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.